

# Product Brief Intel® NAND Storage Solutions

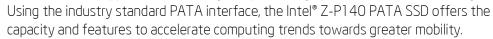
# Intel® Z-P140 PATA Solid State Drive

Enabling smaller, faster, and lighter computing through storage innovation



#### **Product Overview**

The Intel® Z-P140 PATA Solid State Drive (SSD) is an ultra-small, complete storage solution for mobile, digital entertainment, and embedded applications, offering low-power, high performance, and durability.





Specifically designed for small form factor requirements, the Intel® Z-P140 PATA SSD is small and lighter than a coin, the ideal solution to meet the next generation of ultramobile computing.

## Right Fit

Using the standard PATA interface, chipscale package-on-package technology, and a form factor significantly smaller than hard disk drives, the Z-P140 PATA SSD enables smaller and easier storage design.

## **Right Capacity**

2, 4, 8, and 16GB capacities are enough to support operating system storage, applications, data, and media storage, meeting mainstream density requirements for most computing markets.

#### Right Performance

Fast to boot, load, and run applications, with low power and extended durability, solid state technology has no moving parts, allowing for faster system response and longer battery life.

# Intel® Z-P140 PATA Solid State Drive Specifications

Features	Benefits
Solid State Performance	Faster random access due to no mechanical latency
Greener Technology	No spinning platters means lower power consumption
Smaller Size	400x smaller than a 1.8" hard-drive for small form factors
Light Weight	As light as a standard paper clip
Standard Interface	PATA interface is natively supported by standard Operating Systems
Flexible Capacity	Capacity expandable by adding up to three additional NAND devices

#### **Technical Specifications**

Model NameIntel® Z-P140 PATA Solid State DriveCapacity2GB - 4GB, expandable up to 16GB

**Size** 12 x 18 x 1.8mm

Weight 0.6 grams

Interface Parallel-ATA (IDE)

Form Factor

Ultra-Small Package-on-Package BGA Solution

NAND Devices

Intel® NAND Flash Memory SD54B and SD58B

**Read Throughput**40 Megabytes / sec **Write Throughput**30 Megabytes / sec

Power Consumption Idle: 1.1mW Operating: 300mW Typical

Mean-Time Between Failures 2,500,000 hours

Voltage 3.3v I/O and Control Voltages

**Operating Temperature** 0°C to +70°C

**Humidity Non-Operating** 5% to 95% RH non-condensing (at temperatures 25°C-80°C) **RoHS Compliance** Meets the requirements of the EU RoHS Compliance Directives

#### For more information, visit www.intel.com/go/nand

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